74HC2G14; 74HCT2G14

Dual inverting Schmitt trigger

Rev. 4 — 4 December 2023

Product data sheet

1. General description

The 74HC2G14; 74HCT2G14 is a dual inverter with Schmitt-trigger inputs. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} . Schmitt trigger inputs transform slowly changing input signals into sharply defined jitter-free output signals.

2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
 - For 74HC2G14: CMOS level
 - For 74HCT2G14: TTL level
- · High noise immunity
- · CMOS low power dissipation
- Balanced propagation delays
- Unlimited input rise and fall times
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- · Complies with JEDEC standards
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Applications

- · Wave and pulse shaper for highly noisy environments
- · Astable multivibrators
- · Monostable multivibrators

4. Ordering information

Table 1. Ordering information

Type number Package										
	Temperature range	Name	Description	Version						
74HC2G14GW 74HCT2G14GW	-40 °C to +125 °C	TSSOP6	plastic thin shrink small outline package; 6 leads; body width 1.25 mm	SOT363-2						
74HC2G14GV 74HCT2G14GV	-40 °C to +125 °C	SC-74; TSOP6	plastic surface-mounted package; 6 leads	<u>SOT457</u>						



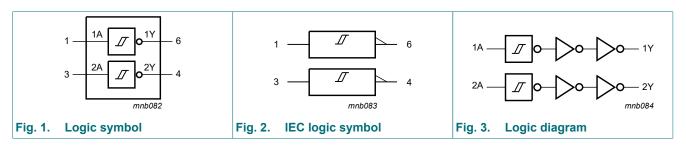
5. Marking

Table 2. Marking

Type number	Marking code[1]
74HC2G14GW	нк
74HCT2G14GW	тк
74HC2G14GV	H14
74HCT2G14GV	T14

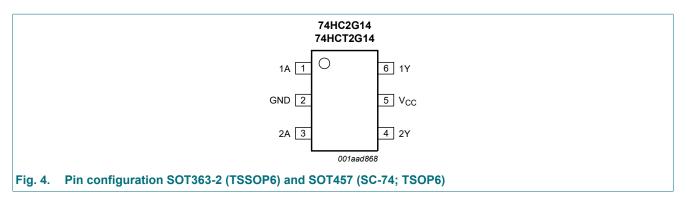
^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram



7. Pinning information

7.1. Pinning



7.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
1A	1	data input
GND	2	ground (0 V)
2A	3	data input
2Y	4	data output
V _{CC}	5	supply voltage
1Y	6	data output

8. Functional description

Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

Input	Output
nA	nY
L	Н
Н	L

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	[1]	-	±20	mA
I _{OK}	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$	[1]	-	±20	mA
Io	output current	$V_{O} = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$	[1]	-	±25	mA
I _{CC}	supply current		[1]	-	+50	mA
I _{GND}	ground current		[1]	-	-50	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation		[2]	-	250	mW

^[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit				
74HC2G	74HC2G14									
V _{CC}	supply voltage		2.0	5.0	6.0	V				
VI	input voltage		0	-	V _{CC}	V				
Vo	output voltage		0	-	V _{CC}	V				
T _{amb}	ambient temperature		-40	+25	+125	°C				
74HCT2	G14									
V _{CC}	supply voltage		4.5	5.0	5.5	V				
VI	input voltage		0	-	V _{CC}	V				
Vo	output voltage		0	-	V _{CC}	V				
T _{amb}	ambient temperature		-40	+25	+125	°C				

^[2] For SOT363-2 (TSSOP6) package: P_{tot} derates linearly with 3.7 mW/K above 83 °C. For SOT457 (SC-74; TSOP6) package: P_{tot} derates linearly with 4.1 mW/K above 89 °C.

11. Static characteristics

Table 7. Static characteristics for 74HC2G14

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5°C					
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
VOH		I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	4.18	4.32	-	V
		I _O = -5.2 mA; V _{CC} = 6.0 V	5.68	5.81	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	V
I _I	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±0.1	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \mu A; V_{CC} = 6.0 \text{ V}$	-	-	1.0	μA
Cı	input capacitance		-	2.0	-	pF
T _{amb} = -	40 °C to +85 °C					
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = -20 μA; V _{CC} = 2.0 V	1.9	-	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	-	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	-	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	4.13	-	-	V
		I _O = -5.2 mA; V _{CC} = 6.0 V;	5.63	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 2.0 V	-	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	-	0.1	V
		$I_{O} = 20 \mu A; V_{CC} = 6.0 V$		-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	-	0.33	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	-	0.33	V
I _I	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μΑ
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \mu A; V_{CC} = 6.0 \text{ V}$	-	-	10.0	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +125 °C		'			
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = -20 μA; V _{CC} = 2.0 V	1.9	-	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	-	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	-	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	3.7	-	-	V
		I _O = -5.2 mA; V _{CC} = 6.0 V;	5.2	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 2.0 V	-	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	-	0.4	V
I _I	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μA
I _{CC}	supply current	V_I = GND or V_{CC} ; I_O = 0 μ A; V_{CC} = 6.0 V	-	-	20.0	μΑ

Table 8. Static characteristics for 74HCT2G14

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C		-	1		
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = -20 μA; V _{CC} = 4.5 V		4.5	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	4.18	4.32	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	V
l _l	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	±0.1	μΑ
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \mu A; V_{CC} = 5.5 \text{ V}$	-	-	1.0	μΑ
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 2.1 \text{ V}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; I_O = 0 \mu\text{A}$	-	-	300	μΑ
Cı	input capacitance		-	2.0	-	pF
T _{amb} = -	40 °C to +85 °C		1	1		
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	-	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	4.13	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 4.5 V	-	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	-	0.33	V
I _I	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μA
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \mu\text{A}; V_{CC} = 5.5 \text{ V}$	-	-	10.0	μA
Δl _{CC}	additional supply current	$V_1 = V_{CC} - 2.1 \text{ V}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; I_O = 0 \mu\text{A}$	-	-	375	μΑ

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	40 °C to +125 °C					
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	-	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	3.7	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I _O = 20 μA; V _{CC} = 4.5 V	-	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	-	0.4	V
I _I	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μA
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 μ A; V_{CC} = 5.5 V	-	-	20.0	μA
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 2.1 \text{ V}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; I_O = 0 \mu\text{A}$	-	-	410	μΑ

12. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6.

Symbol	Parameter	Conditions			25 °C		-40 °C to	o +85 °C	-40 °C to	+125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	
74HC2G	14					•					
t _{pd}	propagation	nA to nY; see Fig. 5	[1]								
	delay	V_{CC} = 2.0 V; C_L = 50 pF		-	53	125	-	155	-	190	ns
		$V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$		-	16	25	-	31	-	38	ns
		$V_{CC} = 6.0 \text{ V}; C_L = 50 \text{ pF}$		-	13	21	-	26	-	32	ns
t _t	transition time	nY; see <u>Fig. 5</u>	[2]								
		V_{CC} = 2.0 V; C_L = 50 pF		-	20	75	-	95	-	110	ns
		$V_{CC} = 4.5 \text{ V}; C_L = 50 \text{ pF}$		-	7	15	-	19	-	22	ns
		$V_{CC} = 6.0 \text{ V}; C_L = 50 \text{ pF}$		-	5	13	-	16	-	19	ns
C _{PD}	power dissipation capacitance	V _I = GND to V _{CC}	[3]	-	10	-	-	-		-	pF
74HCT2	G14										
t _{pd}	propagation	nA to nY; see Fig. 5	[1]								
	delay	V _{CC} = 4.5 V; C _L = 50 pF		-	21	32	-	40	-	48	ns
t _t	transition time	nY; see Fig. 5	[2]								
		V_{CC} = 4.5 V; C_L = 50 pF		-	6	15	-	19	-	22	ns
C _{PD}	power dissipation capacitance	V_{I} = GND to V_{CC} - 1.5 V	[3]	-	10	-	-	-	-	-	pF

- [1] t_{pd} is the same as t_{PLH} and t_{PHL}
- [2] t_t is the same as t_{TLH} and t_{THL}
 [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

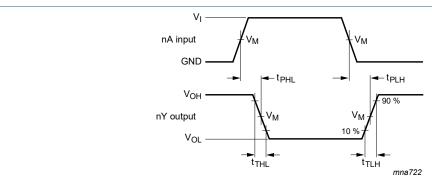
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

12.1. Waveforms and test circuit



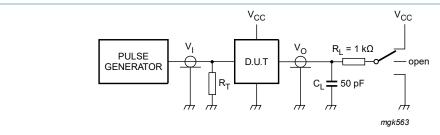
Measurement points are given in <u>Table 10</u>.

 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig. 5. The data input (nA) to output (nY) propagation delays and output transition times

Table 10. Measurement points

The state of the s									
Туре	Input	Output							
	V_{M}	V_{l}	$t_r = t_f$	V_{M}					
74HC2G14	0.5V _{CC}	GND to V _{CC}	6.0 ns	0.5V _{CC}					
74HCT2G14	1.3 V	GND to 3.0 V	6.0 ns	1.3 V					



Test data is given in Table 11.

Definitions test circuit:

 R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

Fig. 6. Test circuit for measuring switching times

Table 11. Test data

Туре	Input	Test	
	V _I	t _r , t _f	t _{PHL} , t _{PLH}
74HC2G14	GND to V _{CC}	6 ns	open
74HCT2G14	GND to 3.0 V	6 ns	open

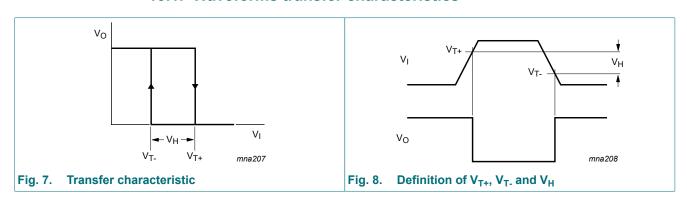
13. Transfer characteristics

Table 12. Transfer characteristics

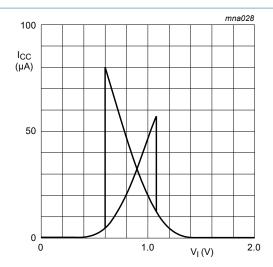
Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6.

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC2G	14				'	1				
	positive-going threshold voltage	see <u>Fig. 7</u> , <u>Fig. 8</u>								
		V _{CC} = 2.0 V	1.00	1.18	1.50	1.00	1.50	1.00	1.50	V
		V _{CC} = 4.5 V	2.30	2.60	3.15	2.30	3.15	2.30	3.15	V
		V _{CC} = 6.0 V	3.00	3.46	4.20	3.00	4.20	3.00	4.20	V
V _T -	negative-going	see <u>Fig. 7</u> , <u>Fig. 8</u>								
	threshold voltage	V _{CC} = 2.0 V	0.30	0.60	0.90	0.30	0.90	0.30	0.90	V
		V _{CC} = 4.5 V	1.13	1.47	2.00	1.13	2.00	1.13	2.00	V
		V _{CC} = 6.0 V	1.50	2.06	2.60	1.50	2.60	1.50	2.60	V
V _H	hysteresis voltage	(V _{T+} - V _{T-}); see <u>Fig. 7</u> , <u>Fig. 8</u> and <u>Fig. 9</u>								
		V _{CC} = 2.0 V	0.30	0.60	1.00	0.30	1.00	0.30	1.00	V
		V _{CC} = 4.5 V	0.60	1.13	1.40	0.60	1.40	0.60	1.40	V
		V _{CC} = 6.0 V	0.80	1.40	1.70	0.80	1.70	0.80	1.70	V
74HCT2	G14		'		•					
	positive-going threshold voltage	see Fig. 7 and Fig. 8								
		V _{CC} = 4.5 V	1.20	1.58	1.90	1.20	1.90	1.20	1.90	V
		V _{CC} = 5.5 V	1.40	1.78	2.10	1.40	2.10	1.40	2.10	V
	negative-going threshold voltage	see Fig. 7 and Fig. 8								
		V _{CC} = 4.5 V	0.50	0.87	1.20	0.50	1.20	0.50	1.20	V
		V _{CC} = 5.5 V	0.60	1.11	1.40	0.60	1.40	0.60	1.40	V
V _H	hysteresis voltage	(V _{T+} - V _{T-}); see <u>Fig. 7</u> , <u>Fig. 8</u> and <u>Fig. 10</u>								
		V _{CC} = 4.5 V	0.40	0.71	-	0.40	-	0.40	-	V
		V _{CC} = 5.5 V	0.40	0.67	-	0.40	-	0.40	-	V

13.1. Waveforms transfer characteristics



74HC_HCT2G14





c. V_{CC} = 6.0 V

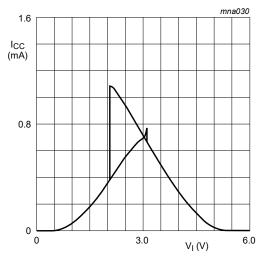
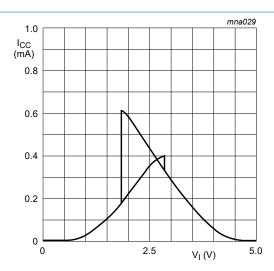


Fig. 9. Typical 74HC2G14 transfer characteristics



b.
$$V_{CC} = 4.5 \text{ V}$$

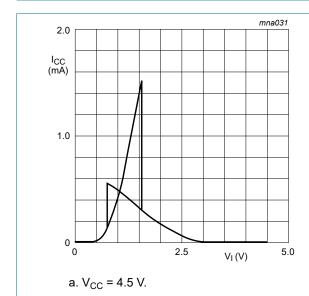
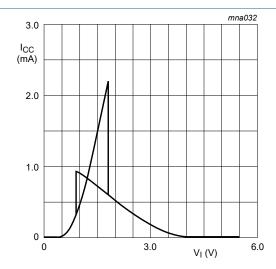


Fig. 10. Typical 74HCT2G14 transfer characteristics



b. $V_{CC} = 5.5 \text{ V}$.

14. Application information

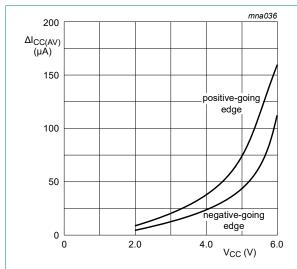
The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

 $P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC}$ where:

- P_{add} = additional power dissipation (μW);
- f_i = input frequency (MHz);
- t_r = input rise time (ns); 10 % to 90 %;
- t_f = input fall time (ns); 90 % to 10 %;
- ΔI_{CC(AV)} = average additional supply current (µA).

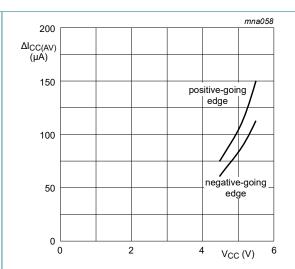
 $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in Fig. 11 and Fig. 12.

An example of a relaxation circuit using the 74HC2G14; 74HCT2G14 is shown in Fig. 13.



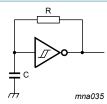
Linear change of V_I between 0.1V_{CC} to 0.9V_{CC}

Fig. 11. $\Delta I_{CC(AV)}$ as a function of V_{CC} for 74HC2G14



Linear change of V_I between $0.1V_{CC}$ to $0.9V_{CC}$

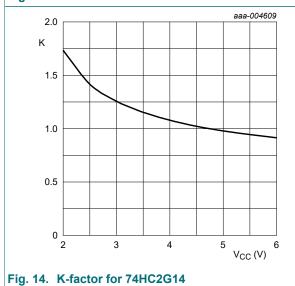
Fig. 12. $\Delta I_{CC(AV)}$ as a function of V_{CC} for 74HCT2G14



For 74HC2G14: $f = \frac{1}{T} \approx \frac{1}{0.8 \times RC}$ For 74HCT2G14: $f = \frac{1}{T} \approx \frac{1}{0.67 \times RC}$

For K-factor, see Fig. 14 or Fig. 15

Fig. 13. Relaxation oscillator



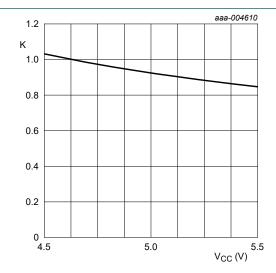


Fig. 15. K-factor for 74HCT2G14

15. Package outline

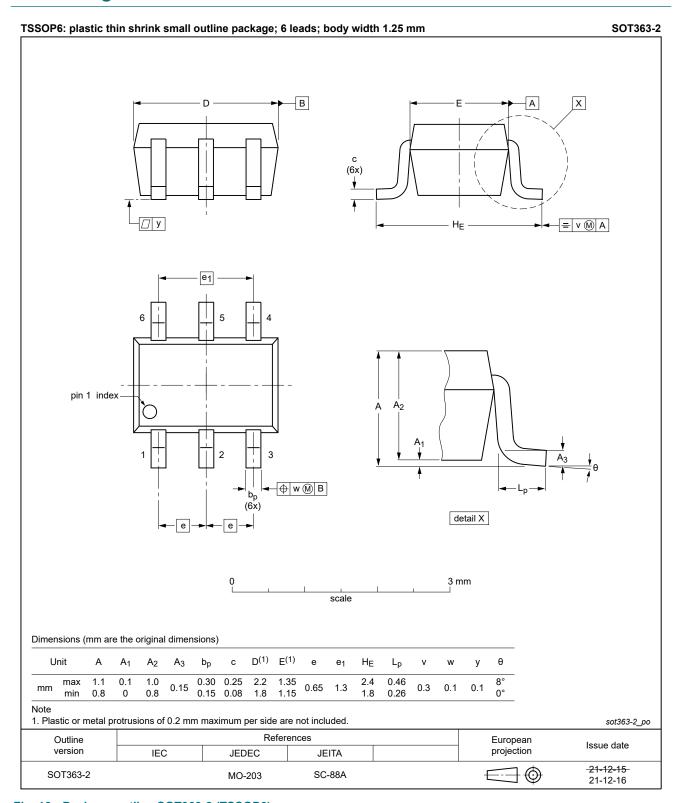


Fig. 16. Package outline SOT363-2 (TSSOP6)

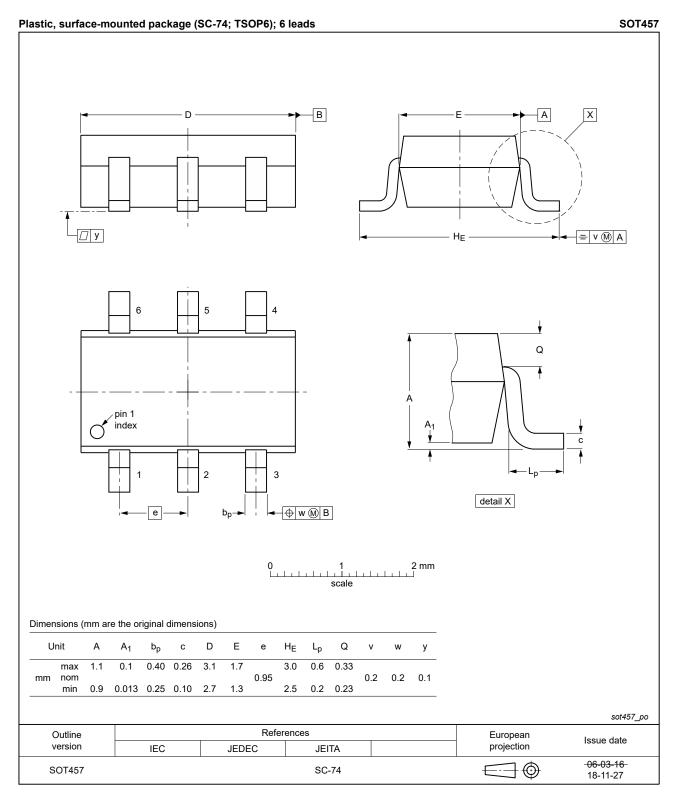


Fig. 17. Package outline SOT457 (SC-74; TSOP6)

16. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charge Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
TTL	Transistor-Transistor Logic

17. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74HC_HCT2G14 v.4	20231204	Product data sheet	-	74HC_HCT2G14 v.3	
Modifications:	Section 2: E	SD specification updated a	according to the la	itest JEDEC standard.	
74HC_HCT2G14 v.3	20220128	Product data sheet	-	74HC_HCT2G14 v.2	
Modifications:	guidelines of Legal texts Package So Section 2 up Section 9: E	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Package SOT363 (SC-88) changed to SOT363-2 (TSSOP6). Section 2 updated. Section 9: Derating values for Ptot total power dissipation updated. Fig. 17: Package outline drawing SOT457 (SC-74; TSOP6) updated. 			
74HC_HCT2G14 v.2	20140314	Product data sheet	-	74HC_HCT2G14 v.1	
Modifications:	• <u>Fig. 14</u> and	Fig. 15 added (typical K-fa	ctor for relaxation	oscillator).	
74HC_HCT2G14 v.1	20061011	Product data sheet	-	-	

18. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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